P ac ical le fo o bi al-con olled fe omagne i m of 3*d* imp i ie in emicond c o

[illegible] E [illegible] C [illegible] 80401

(2 200 2 200 1 200)

[illegible] 2005 A8 [illegible] . [10.10 3/1.212 4 0]

I. INTRODUCTION

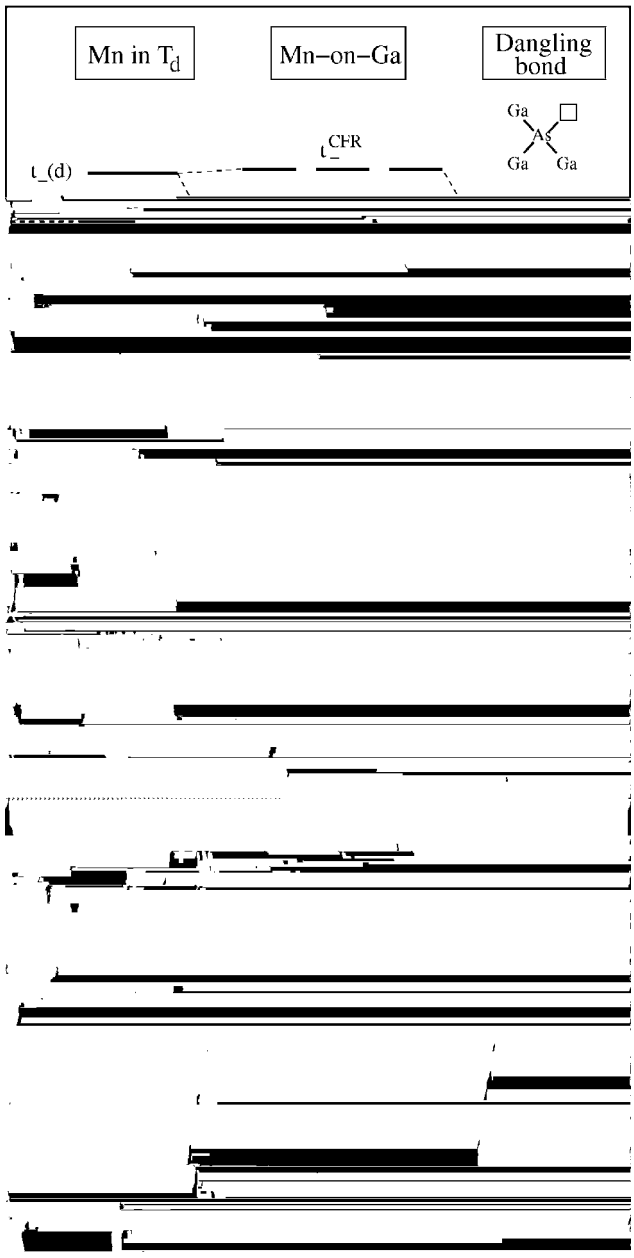
[illegible] 1 0 1 0 [illegible] (10^1 10^1 [illegible] ^{3} [illegible]) [illegible] ^{1} [illegible] 1 0 , [illegible] (10^1 10^{21} [illegible] ^{3} [illegible]) [illegible] 12 [illegible] 3 [illegible] 2 [illegible] 2 [illegible]

[illegible] $_2$ ([illegible]), [illegible] [110] [illegible] $_{11}$ [illegible] c.

II. MAGNETISM AND IMPURITY ORBITAL CHARACTER

[illegible] ([illegible]. 1). [illegible]

(a) GaAs:Mn

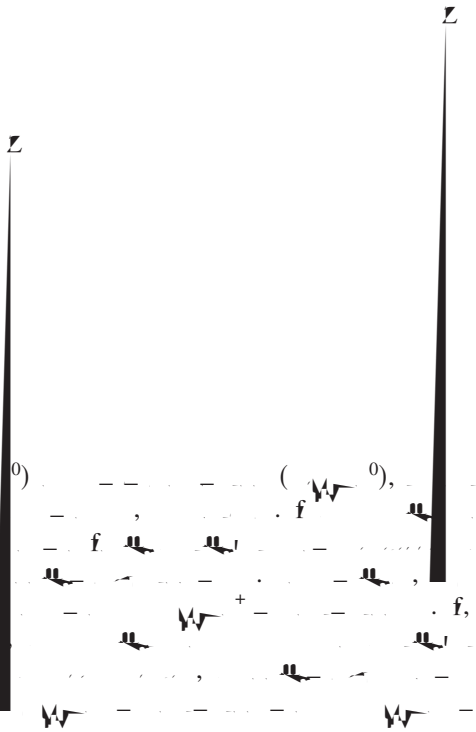
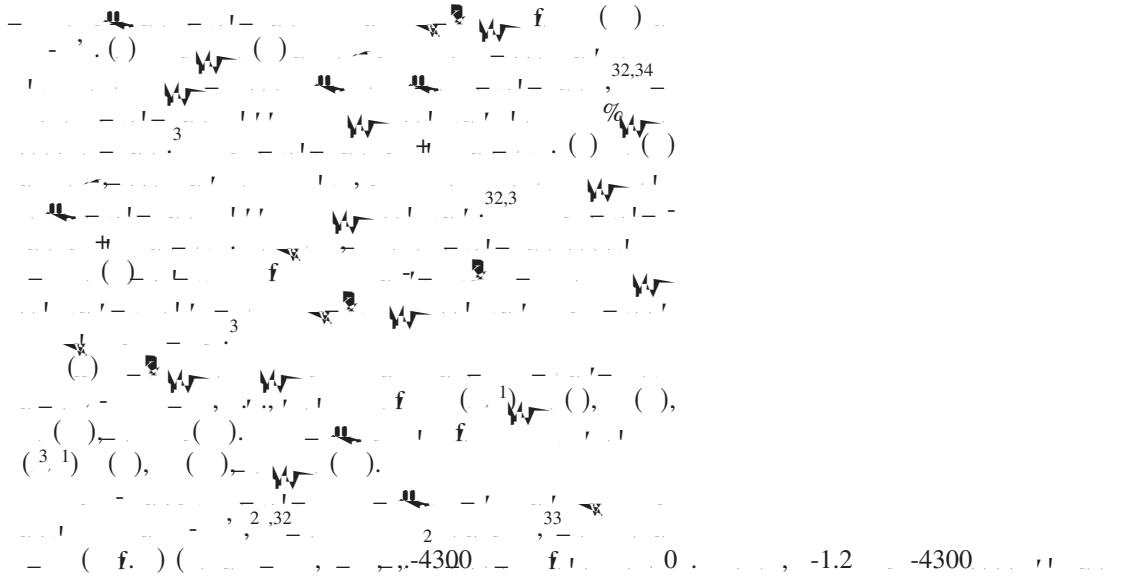


[illegible]

D. The ba ic TM-TM fe omagne ic in e ac ion

[illegible]

III. PRACTICAL RULES

[illegible]

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